

4-Channel MOSFET Switch Driver with Decode

FEATURES

- TTL Compatible
- 4 Independent Drivers
- Output Sink Current to 10 mA
- DC Level Shifts to >19 V

BENEFITS

- Reduces System Component Requirements
- Fast Level Shifting

APPLICATIONS

- Interfacing Low Level Logic to MOSFETs or JFETs
- Designed to Interface with G118 and G119

DESCRIPTION

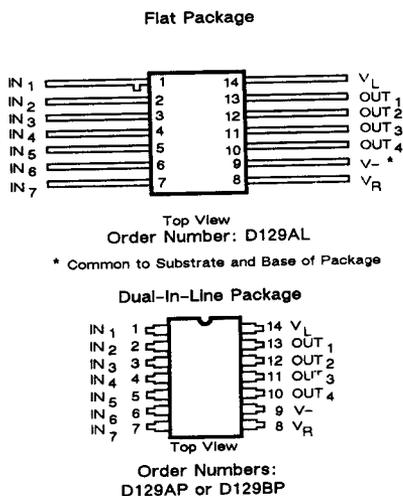
The D129 is a four-channel driver designed to provide the DC level-shifting and amplification functions needed to interface low-level logic outputs (0.7 to 2.2 V) and field-effect transistor switch inputs (up to 50 V peak-to-peak). With an input logic supply of 5 V, the output transistor emitter, (V_-), may be set at any voltage between -5 and -30 V. In the ON state, the output collector will sink up to 10 mA of current, and in the OFF state will hold off voltages up to 50 V above V_- . Each of the four drivers has a 3-input logic gate, and the driver will be ON when each of the inputs

are either open or at positive logic "1".

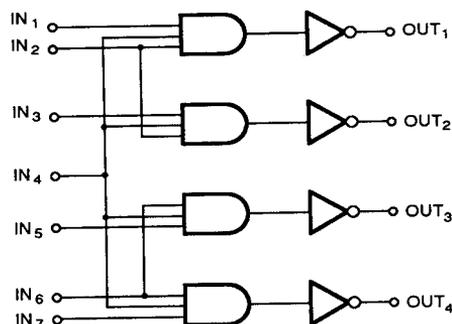
With any of the inputs either grounded or at positive logic "0", the driver will be OFF. Some of the logic inputs to the four gates are internally connected to facilitate decoding from a binary counter, however, one input to each gate provides a means for independent operation of each driver, if desired.

Package options include the 14-pin side braze and flatpack packages. Performance grades include both the industrial, B suffix (-25 to 85°C) and military, A suffix (-55 to 125°C) temperature ranges.

PIN CONFIGURATION



FUNCTIONAL BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

V_O to V_- (A Suffix)	50 V	Operating Temperature (A Suffix)	-55 to 125°C
V_O to V_- (B Suffix)	36 V	(B Suffix)	-25 to 85°C
V_R to V_- (A Suffix)	33 V	Power Dissipation*	
V_R to V_- (B Suffix)	24 V	Flatpack**	750 mW
V_L to V_R	8 V	14-Pin DIP***	825 mW
V_{IN} to V_R	±6 V		
V_{IN} to V_{IN} (Any Other V_{IN} Terminals)	6 V	* All leads soldered or welded to PC board.	
Current, (Any Terminal)	30 mA	** Derate 10 mW/°C above 75°C.	
Storage Temperature	-65 to 150°C	*** Derate 11 mW/°C above 75°C.	

ELECTRICAL CHARACTERISTICS ^a											
PARAMETER	SYMBOL	Test Conditions Unless Otherwise Specified: $V_L = 5 V$ $V_- = -20 V$ $V_R = 0 V$	LIMITS						UNIT		
			1=25°C		A SUFFIX		B SUFFIX				
			TEMP	TYP ^c	MIN ^b	MAX ^b	MIN ^b	MAX ^b			
OUTPUT											
Output Voltage, LOW	V_{OL}	$V_{IN} = 2.2 V$ $V_L = 4.5 V$	$I_{OUT} = 10 mA$	1,3 2	-19.8		-19.3 -19.0		-19.25 -19.0	V	
			$I_{OUT} = 1 mA$	1	-19.75		-19.8				
Output Current, HIGH	I_{OH}	$V_O = 10 V$ $V_{IN} = 0.7 V$		1,3 2	0.005		0.1 20		0.2 10	µA	
INPUT											
Input Current, Voltage HIGH	I_{INH}	$V_{IN} = 5 V$, Input Under Test $V_{IN} = 0 V$, All Other Inputs		1,3 2			0.25 5		1 5	µA	
Input Current, Voltage LOW	I_{INL}	$V_{IN} = 0 V$, $V_L = 5.5 V$		1 2 3	-0.2		-200 -160 -250		-225 -200 -250	µA	
DYNAMIC											
Turn-ON Time	t_{ON}	See Switching Time Test Circuit ($C_L = 35 pF$)		1	0.22		0.3		0.3	µs	
Turn-OFF Time	t_{OFF}			1	1.16		1.5		1.5		
SUPPLY											
Negative Supply Current	I_-	$V_- = -20 V$ $V_L = 5.5 V$	One Channel ON	1	-1.5	-2		-2.25		mA	
Logic Supply Current	I_L			1	2.2		3		3.3		
Negative Supply Current	I_-		All $V_{IN} = 0 V$ All Channels OFF		1	-0.01	-10		-25		µA
Logic Supply Current	I_L			1	0.46		0.75		1		mA

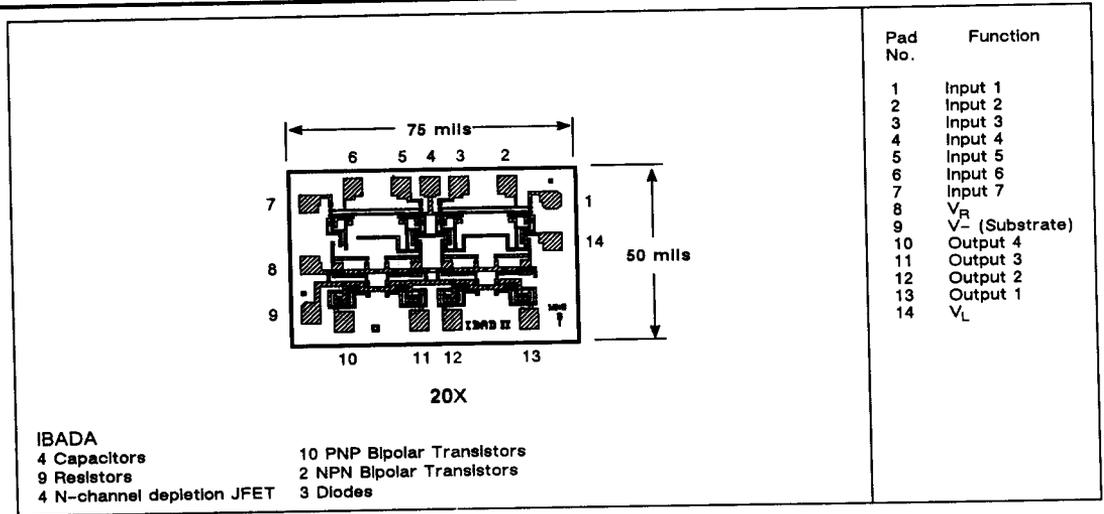
NOTES:

- a. Refer to PROCESS OPTION FLOWCHART for additional information.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

Not Recommended for New Designs



DIE TOPOGRAPHY



SWITCHING TIME AND TEST CIRCUIT

